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Rev. 10/95  U.S. Department of Commerce Patent and Trademark Office	Application Number 10/765,578	
	Filing Date January 26, 200	04
TRANSMITTAL FORM	First Named Inventor Robert A. York	
(to be used for all correspondence during pendency of filed application)	Group Art Unit Number 2811	
·	Examiner Name Not yet known	
Total Number of Pages in This Submission 6	Attorney Docket Number 22994-08791	
ENCLOSURES	(check all that apply)	
Fee Transmittal Form (in duplicate) Check Enclosed  Return Receipt Postcard Response to Notice to File Missing Parts Assignment & Recordation Cover Sheet Declaration Power of Attorney Application Data Sheet Information Disclosure Statement & PTO/SB/08A Copies of IDS Cited References Request for Corrected Filing Receipt Request for Correction of Recorded Assignment Amendment/Response: [] Page(s) After Final Status Request Revocation and Substitute Power of Attorney	Issue Fee Transmittal Letter to Chief Draftsperson Formal Drawing(s):  [ ] Sheet(s) of Figure(s) [ ] Appeal Communication to Board of Appeal Communication to Group (Appeal Notice, Brief, Reply Brief) Certified Copy of Priority Document(s) After Allowance Communication to Group	·
REMARKS:		
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Signature:	ATTORNEY OR AGENT	
Attorney/Reg. No.: Michael W. Farn, Reg. No. 41,015	Dated: May	5, 2004
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Typed or Printed Name: Michael W. Farn	Dated: May	<u></u>
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## O MI O DIL DE LE D

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Robert A. York

APPLICATION NO.:

10/765,578

FILING DATE:

January 26, 2004

TITLE:

Voltage-Variable Capacitor with Increased Current Conducting

Perimeter

**EXAMINER:** 

Not yet known

**GROUP ART UNIT:** 

2811

ATTY. DKT. NO.:

22994-08791

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The filing of this Information Disclosure Statement shall not be construed as a representation regarding the completeness of the list of references, or that inclusion of a reference in this list is an admission that it is prior art or is pertinent to this application, or that a search has been made, or as an admission that the information listed is, or may be considered to be, material to patentability, or that no other material information exists, and shall not be construed as an admission against interest in any manner.

This Information Disclosure Statement is being filed:

within three months of the filing date of the application, or date of entry into the national stage of an international application, or before the mailing date of a first office action on the merits, whichever event last occurred;

			ling of a first official action after the filing of a request for
_			mination (RCE) under 37 CFR § 1.114;
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	occurr	ed, but l	before the mailing date of the first to occur of either: (1) a
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						Respectfully submitted,
					R	ROBERT A. YORK
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Dated:	May	5	· , :	2004	E	sy: phoball W
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Substitute for form 1449A/PTO Complete if Known Application No. 10/765,578 INFORMATION DISCLOSURE Filing Date January 26, 2004 STATEMENT BY APPLICANT **First Named Inventor** Robert A. York Art Unit 2811 **Examiner Name** Not yet known 2 Attorney Docket Number 22994-08791 Sheet of

U.S. PATENT DOCUMENTS						
		Document No.				
Examiner Initials*	Cite No.1	Number – Kind Code² (if known)	Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document		
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		Foreign Patent Document			
Examiner Initials*	Cite No.1	Country Code <sup>3</sup> – Number <sup>4</sup> Kind Code <sup>5</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	τ°
		Tana adda (ii tarani)			

		OTHER REFERENCES – NON-PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	۳⁵
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	Substitute for f	orm 1449/	VPTO	Complete if Known			
INFO		I DIE	CLOSURE	Application No.	10/765,578	-	
				Filing Date	January 26, 2004		
STATEMENT BY APPLICANT				First Named Inventor	Robert A. York	· ·	
				Art Unit	2811		
				Examiner Name	Not yet known		
Sheet	2	of	2	Attorney Docket Number	22994-08791		

		OTHER REFERENCES – NON-PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T <sup>6</sup>
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Examiner Signature	Date Considered	
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